

NCP5111

High Voltage, High and Low Side Driver

The NCP5111 is a high voltage power gate driver providing two outputs for direct drive of 2 N-channel power MOSFETs or IGBTs arranged in a half-bridge configuration.

It uses the bootstrap technique to ensure a proper drive of the high-side power switch.

Features

- High Voltage Range: up to 600 V
- dV/dt Immunity ± 50 V/nsec
- Gate Drive Supply Range from 10 V to 20 V
- High and Low Drive Outputs
- Output Source / Sink Current Capability 250 mA / 500 mA
- 3.3 V and 5 V Input Logic Compatible
- Up to V_{CC} Swing on Input Pins
- Extended Allowable Negative Bridge Pin Voltage Swing to -10 V for Signal Propagation
- Matched Propagation Delays between Both Channels
- One Input with Internal Fixed Dead Time (650 ns)
- Under V_{CC} LockOut (UVLO) for Both Channels
- Pin-to-Pin Compatible with Industry Standards
- These are Pb-Free Devices

Typical Applications

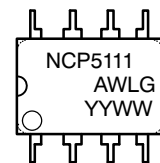
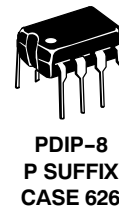
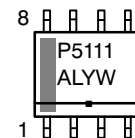
- Half-bridge Power Converters



ON Semiconductor®

<http://onsemi.com>

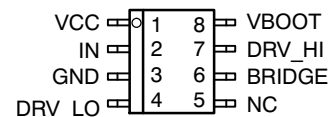
MARKING DIAGRAMS



NCP5111 = Specific Device Code
A = Assembly Location
L or WL = Wafer Lot
Y or YY = Year
W or WW = Work Week
G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

PINOUT INFORMATION



ORDERING INFORMATION

Device	Package	Shipping†
NCP5111PG	PDIP-8 (Pb-Free)	50 Units / Rail
NCP5111DR2G	SOIC-8 (Pb-Free)	2500 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NCP5111

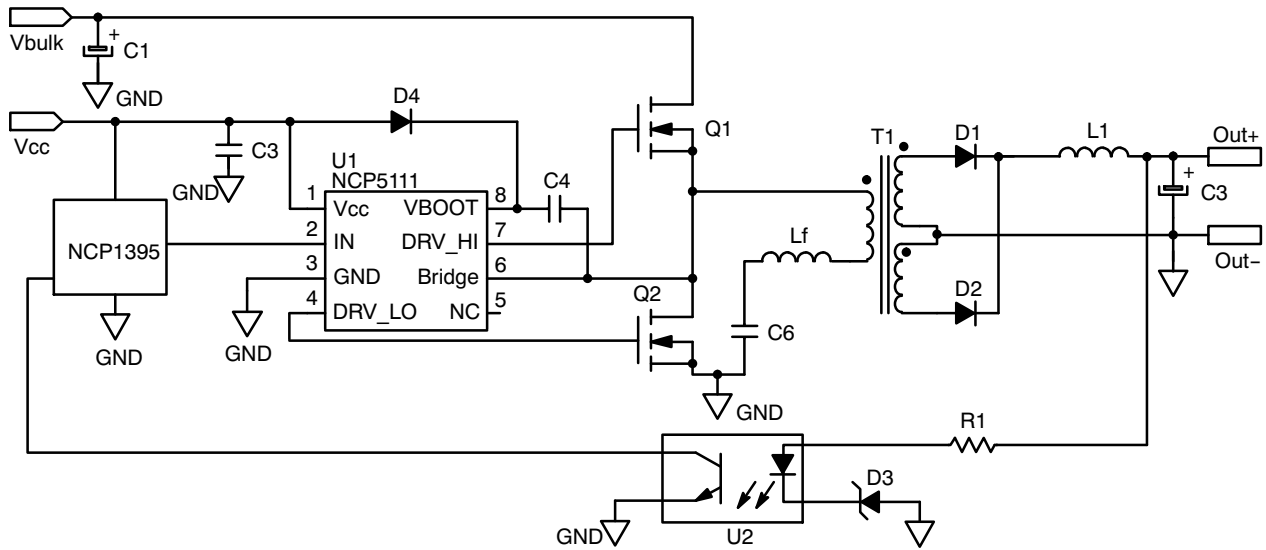


Figure 1. Typical Application Resonant Converter (LLC type)

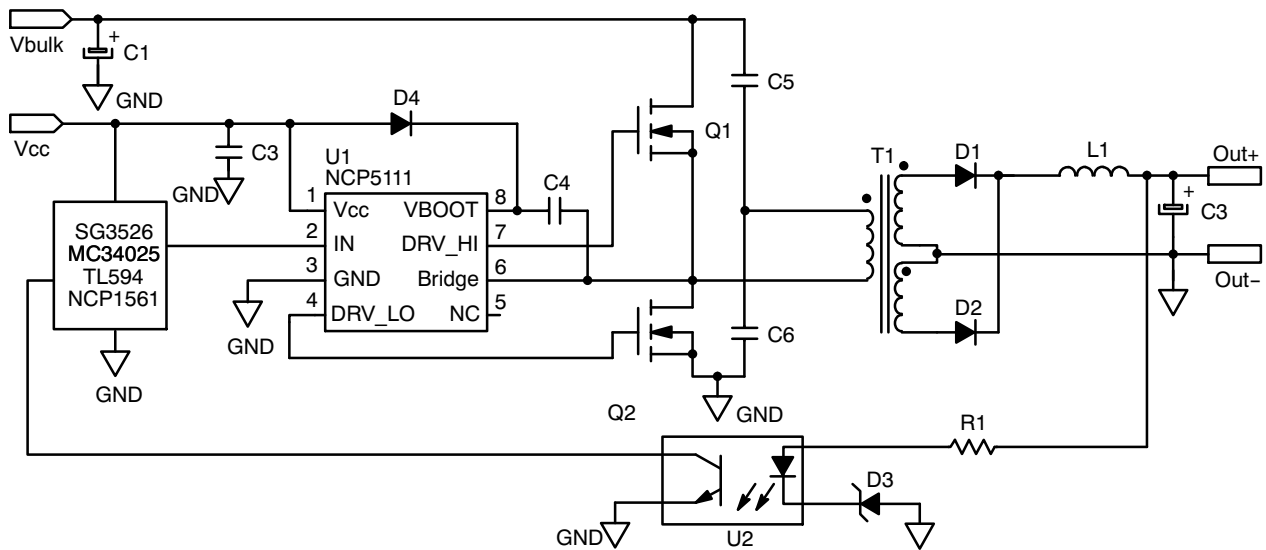


Figure 2. Typical Application Half Bridge Converter

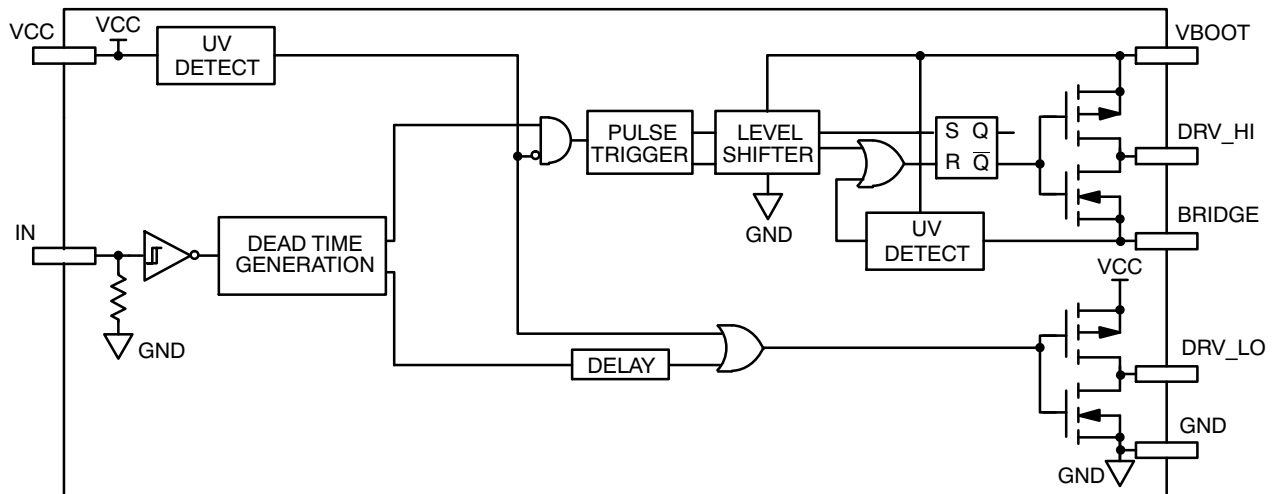


Figure 3. Detailed Block Diagram

NCP5111

PIN DESCRIPTIONS

Pin No.	Pin Name	Pin Function
1	VCC	Low side and main power supply
2	IN	Logic Input
3	GND	Ground
4	DRV_LO	Low side gate drive output
5	NC	Not Connected
6	BRIDGE	Bootstrap return or high side floating supply return
7	DRV_HI	High side gate drive output
8	VBOOT	Bootstrap power supply

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
V_{CC}	Main power supply voltage	-0.3 to 20	V
$V_{CC_transient}$	Main transient power supply voltage: $I_{V_{CC_max}} = 5 \text{ mA}$ during 10 ms	23	V
V_{BRIDGE}	VHV: High Voltage BRIDGE pin	-1 to 600	V
V_{BRIDGE}	Allowable Negative Bridge Pin Voltage for IN_LO Signal Propagation to DRV_LO	-10	V
$V_{BOOT}-V_{BRIDGE}$	VHV: Floating supply voltage	-0.3 to 20	V
V_{DRV_HI}	VHV: High side output voltage	$V_{BRIDGE} - 0.3$ to $V_{BOOT} + 0.3$	V
V_{DRV_LO}	Low side output voltage	-0.3 to $V_{CC} + 0.3$	V
dV_{BRIDGE}/dt	Allowable output slew rate	50	V/ns
V_{IN}	Inputs IN	-1.0 to $V_{CC} + 0.3$	V
	ESD Capability: - HBM model (all pins except pins 6-7-8) - Machine model (all pins except pins 6-7-8)	2 200	kV V
	Latchup capability per JEDEC JESD78		
$R_{\theta JA}$	Power dissipation and Thermal characteristics PDIP-8: Thermal Resistance, Junction-to-Air SO-8: Thermal Resistance, Junction-to-Air	100 178	$^{\circ}\text{C}/\text{W}$
T_{J_max}	Maximum Operating Junction Temperature	+150	$^{\circ}\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

NCP5111

ELECTRICAL CHARACTERISTIC ($V_{CC} = V_{boot} = 15\text{ V}$, $V_{GND} = V_{bridge}$, $-40^{\circ}\text{C} < T_J < 125^{\circ}\text{C}$, Outputs loaded with 1 nF)

Rating	Symbol	$T_J -40^{\circ}\text{C to }125^{\circ}\text{C}$			Units
		Min	Typ	Max	

OUTPUT SECTION

Output high short circuit pulsed current $V_{DRV} = 0\text{ V}$, $PW \leq 10\ \mu\text{s}$ (Note 1)	$I_{DRVsource}$	-	250	-	mA
Output low short circuit pulsed current $V_{DRV} = V_{CC}$, $PW \leq 10\ \mu\text{s}$ (Note 1)	$I_{DRVsink}$	-	500	-	mA
Output resistor (Typical value @ 25°C) Source	R_{OH}	-	30	60	Ω
Output resistor (Typical value @ 25°C) Sink	R_{OL}	-	10	20	Ω
High level output voltage, $V_{BIAS} - V_{DRV_XX}$ @ $I_{DRV_XX} = 20\text{ mA}$	V_{DRV_H}	-	0.7	1.6	V
Low level output voltage V_{DRV_XX} @ $I_{DRV_XX} = 20\text{ mA}$	V_{DRV_L}	-	0.2	0.6	V

DYNAMIC OUTPUT SECTION

Turn-on propagation delay ($V_{bridge} = 0\text{ V}$) (Note 2)	t_{ON}	-	750	1170	ns
Turn-off propagation delay ($V_{bridge} = 0\text{ V}$ or 50 V) (Notes 2 and 3)	t_{OFF}	-	100	170	ns
Output voltage rise time (from 10% to 90% @ $V_{CC} = 15\text{ V}$) with 1 nF load	t_r	-	85	160	ns
Output voltage fall time (from 90% to 10% @ $V_{CC} = 15\text{ V}$) with 1 nF load	t_f	-	35	75	ns
Propagation delay matching between the High side and the Low side @ 25°C (Note 4)	Δt	-	30	60	ns
Internal fixed dead time (Note 5)	DT	400	650	1000	ns

INPUT SECTION

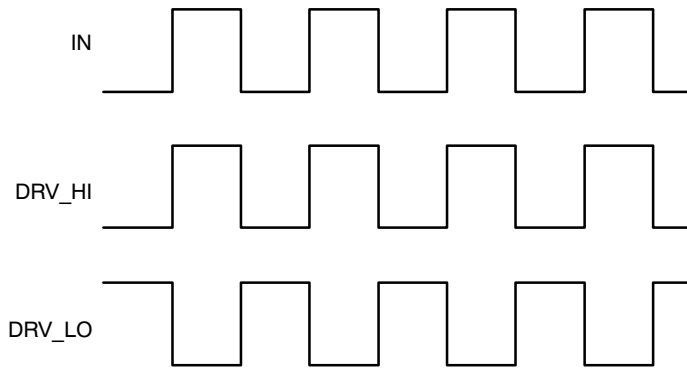
Low level input voltage threshold	V_{IN}	-	-	0.8	V
Input pull-down resistor ($V_{IN} < 0.5\text{ V}$)	R_{IN}	-	200	-	k Ω
High level input voltage threshold	V_{IN}	2.3	-	-	V
Logic "1" input bias current @ $V_{IN} = 5\text{ V}$ @ 25°C	I_{IN+}	-	5	25	μA
Logic "0" input bias current @ $V_{IN} = 0\text{ V}$ @ 25°C	I_{IN-}	-	-	2.0	μA

SUPPLY SECTION

Vcc UV Start-up voltage threshold	V_{cc_stup}	8.0	8.9	9.9	V
Vcc UV Shut-down voltage threshold	V_{cc_shtdwn}	7.3	8.2	9.1	V
Hysteresis on Vcc	V_{cc_hyst}	0.3	0.7	-	V
Vboot Start-up voltage threshold reference to bridge pin ($V_{boot_stup} = V_{boot} - V_{bridge}$)	V_{boot_stup}	8.0	8.9	9.9	V
Vboot UV Shut-down voltage threshold	V_{boot_shtdwn}	7.3	8.2	9.1	V
Hysteresis on Vboot	V_{boot_shtdwn}	0.3	0.7	-	V
Leakage current on high voltage pins to GND ($V_{BOOT} = V_{BRIDGE} = DRV_HI = 600\text{ V}$)	I_{HV_LEAK}	-	5	40	μA
Consumption in active mode ($V_{CC} = V_{boot}$, $f_{sw} = 100\text{ kHz}$ and 1 nF load on both driver outputs)	ICC1	-	4	5	mA
Consumption in inhibition mode ($V_{CC} = V_{boot}$)	ICC2	-	250	400	μA
Vcc current consumption in inhibition mode	ICC3	-	200	-	μA
Vboot current consumption in inhibition mode	ICC4	-	50	-	μA

1. Parameter guaranteed by design.
2. $T_{ON} = T_{OFF} + DT$.
3. Turn-off propagation delay @ $V_{bridge} = 600\text{ V}$ is guaranteed by design.
4. See characterization curve for Δt parameters variation on the full range temperature.
5. Timing diagram definition see: Figure 5 and Figure 6.

NCP5111



Note: DRV_HI output is in phase with the input.

Figure 4. Input/Output Timing Diagram

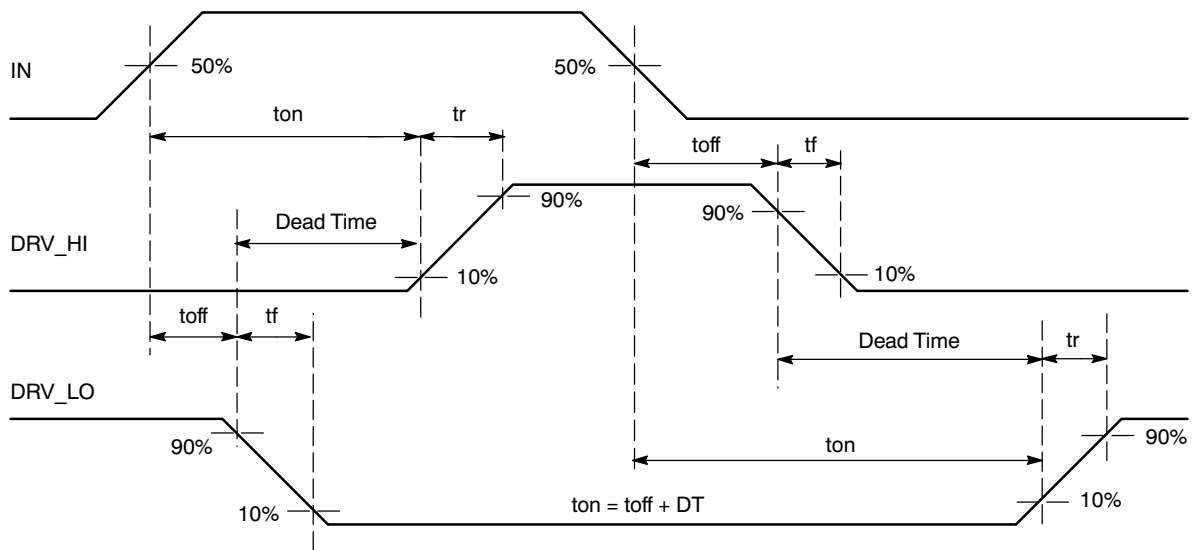


Figure 5. Timing Definitions

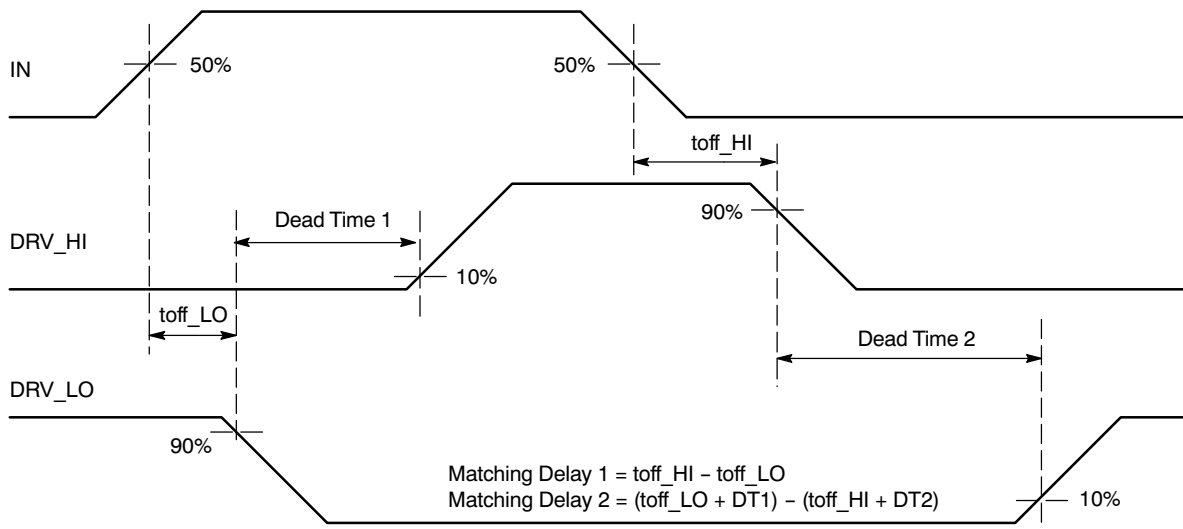


Figure 6. Matching Propagation Delay

CHARACTERIZATION CURVES

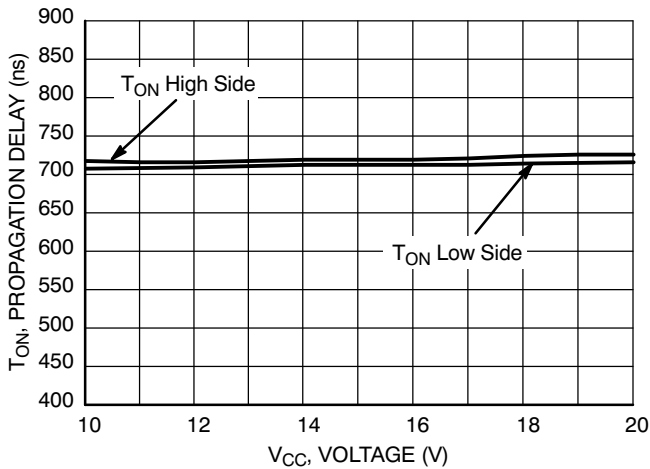


Figure 7. Turn ON Propagation Delay vs. Supply Voltage ($V_{CC} = V_{BOOT}$)

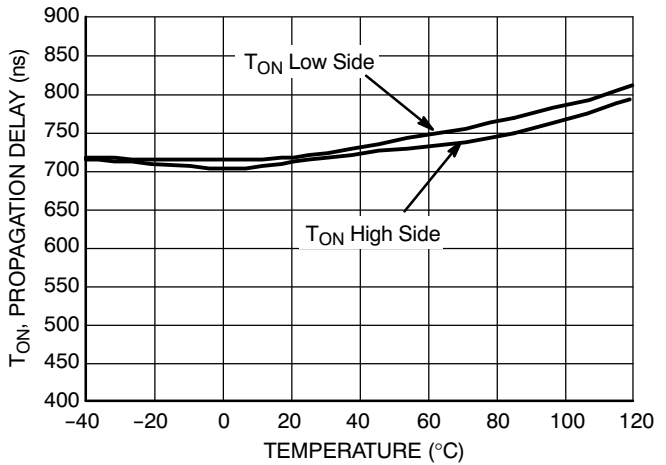


Figure 8. Turn ON Propagation Delay vs. Temperature

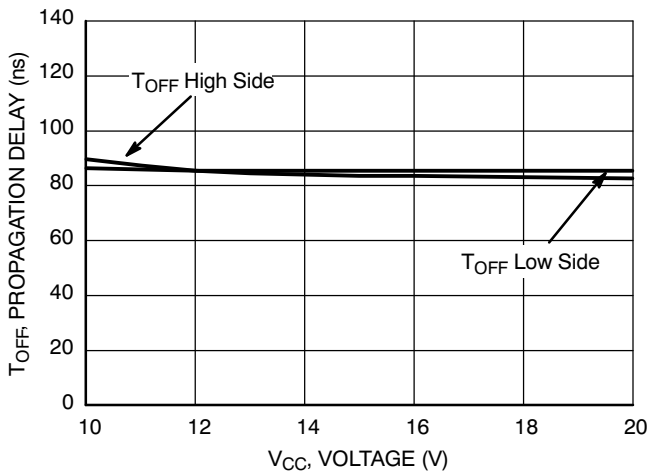


Figure 9. Turn OFF Propagation Delay vs. Supply Voltage ($V_{CC} = V_{BOOT}$)

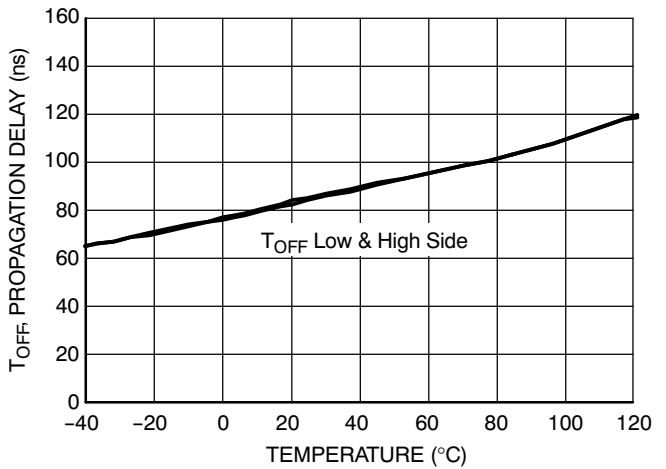


Figure 10. Turn OFF Propagation Delay vs. Temperature

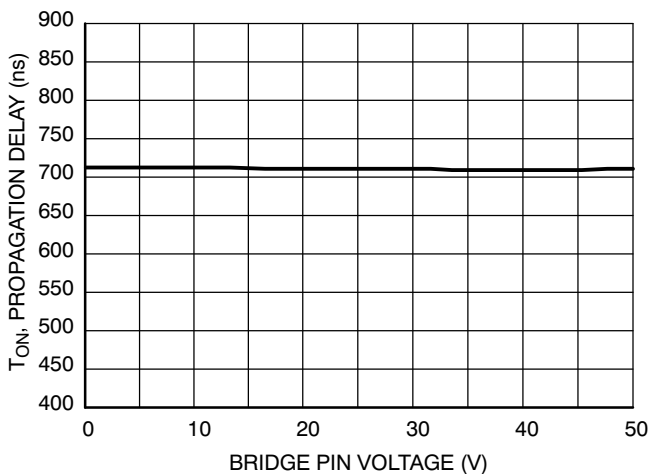


Figure 11. High Side Turn ON Propagation Delay vs. V_{BRIDGE} Voltage

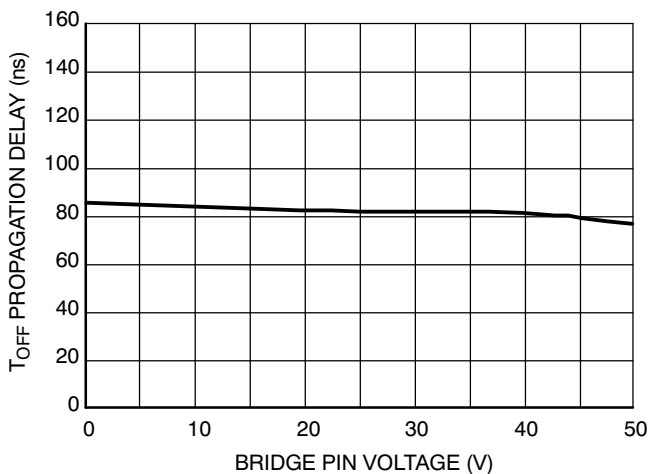


Figure 12. High Side Turn OFF Propagation Delay vs. V_{BRIDGE} Voltage

CHARACTERIZATION CURVES

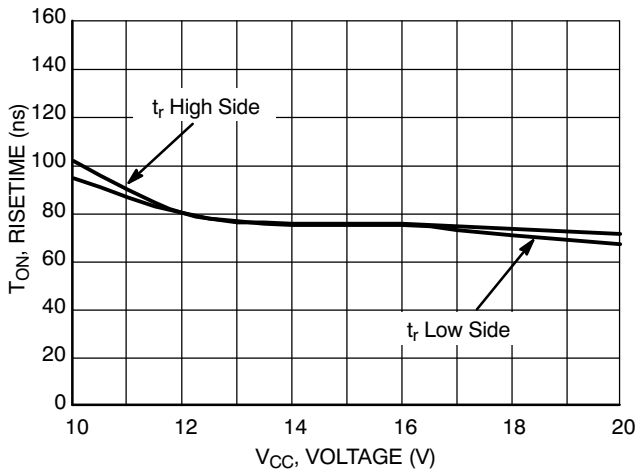


Figure 13. Turn ON Risetime vs. Supply Voltage ($V_{CC} = V_{BOOT}$)

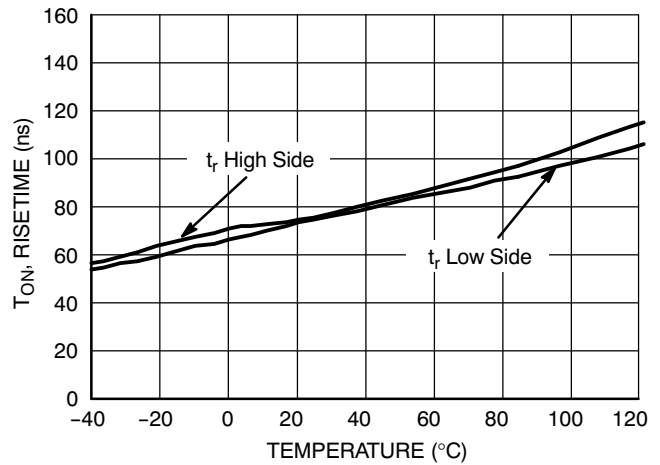


Figure 14. Turn ON Risetime vs. Temperature

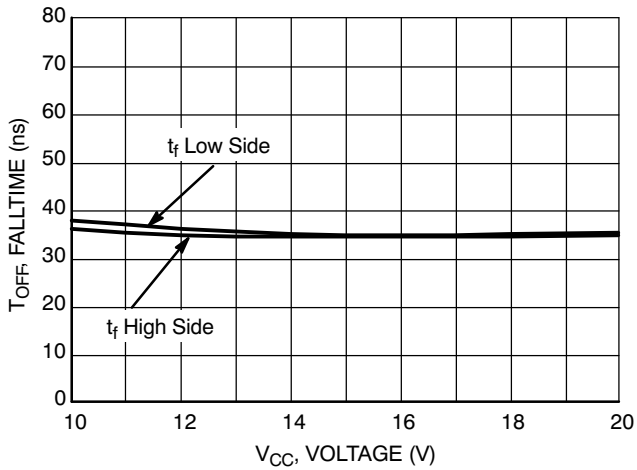


Figure 15. Turn OFF Falltime vs. Supply Voltage ($V_{CC} = V_{BOOT}$)

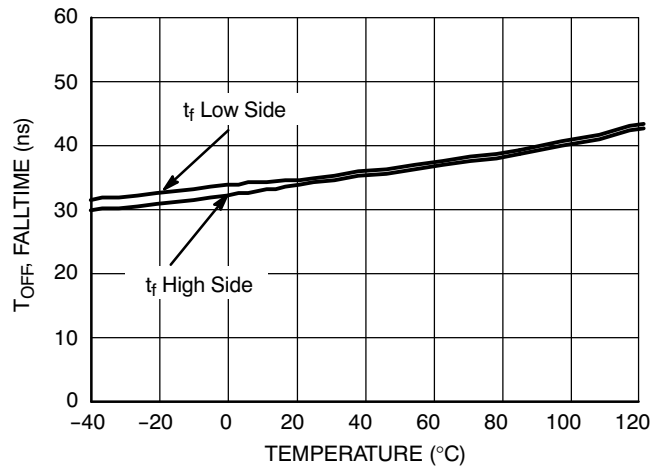


Figure 16. Turn OFF Falltime vs. Temperature

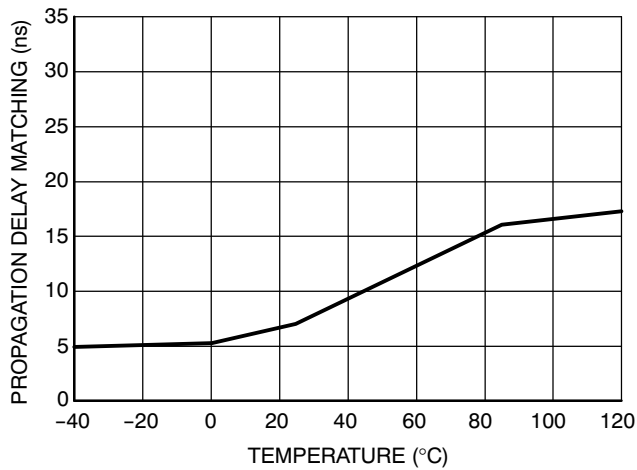


Figure 17. Propagation Delay Matching Between High Side and Low Side Driver vs. Temperature

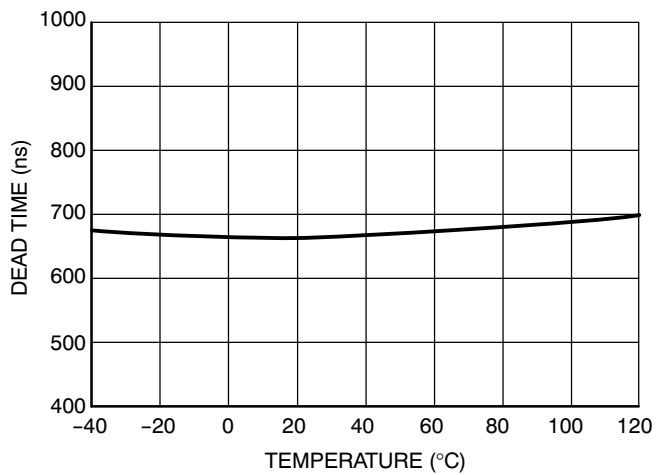


Figure 18. Dead Time vs. Temperature

CHARACTERIZATION CURVES

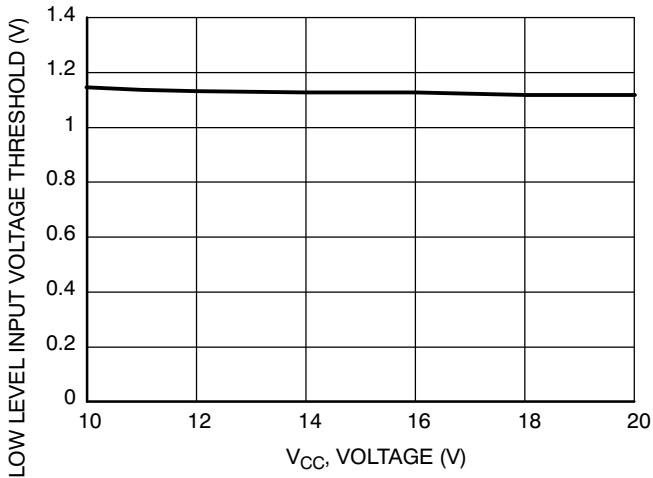


Figure 19. Low Level Input Voltage Threshold vs. Supply Voltage ($V_{CC} = V_{BOOT}$)

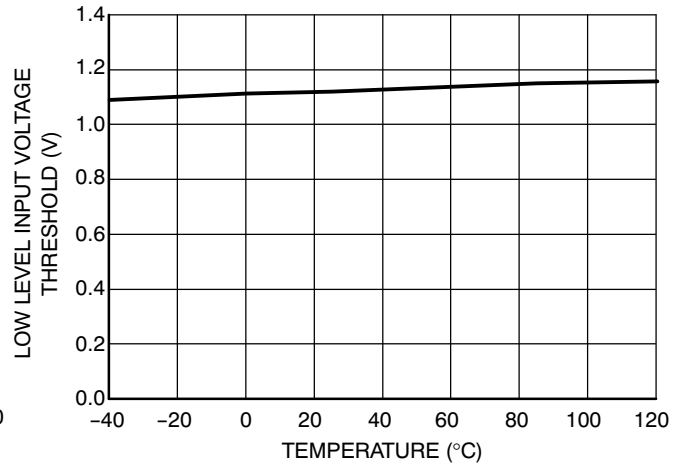


Figure 20. Low Level Input Voltage Threshold vs. Temperature

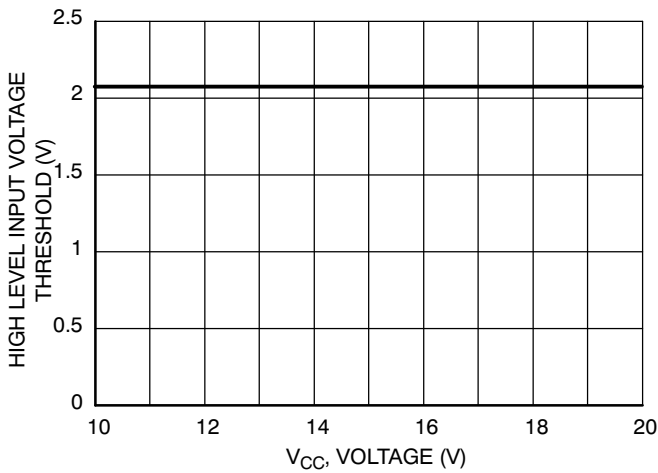


Figure 21. High Level Input Voltage Threshold vs. Supply Voltage ($V_{CC} = V_{BOOT}$)

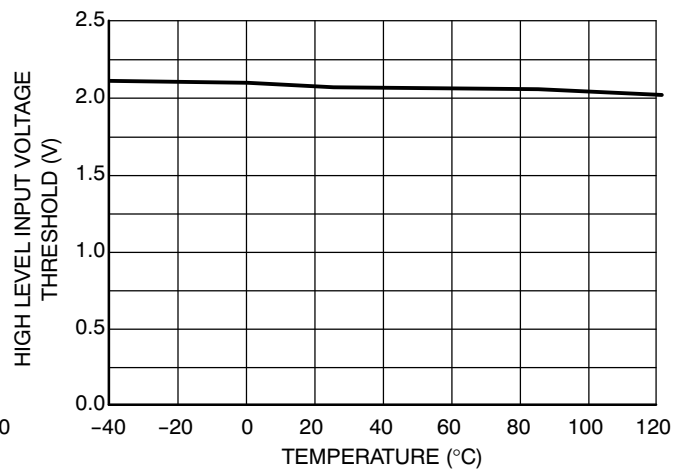


Figure 22. High Level Input Voltage Threshold vs. Temperature

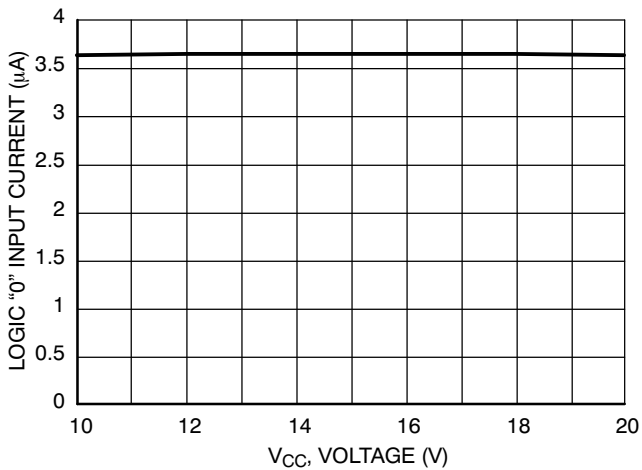


Figure 23. Logic "0" Input Current vs. Supply Voltage ($V_{CC} = V_{BOOT}$)

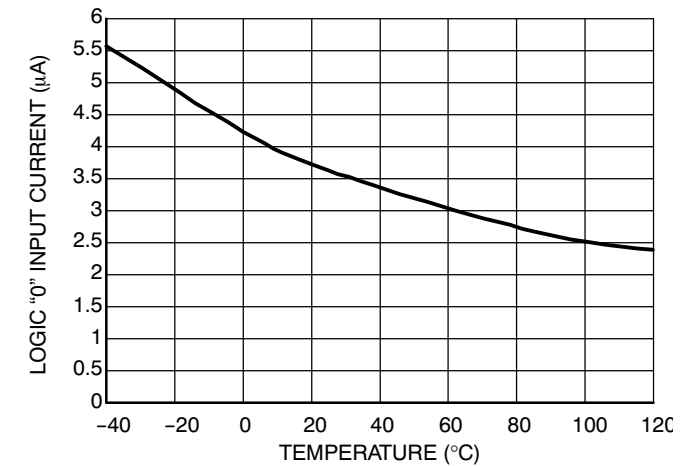


Figure 24. Logic "0" Input Current vs. Temperature

CHARACTERIZATION CURVES

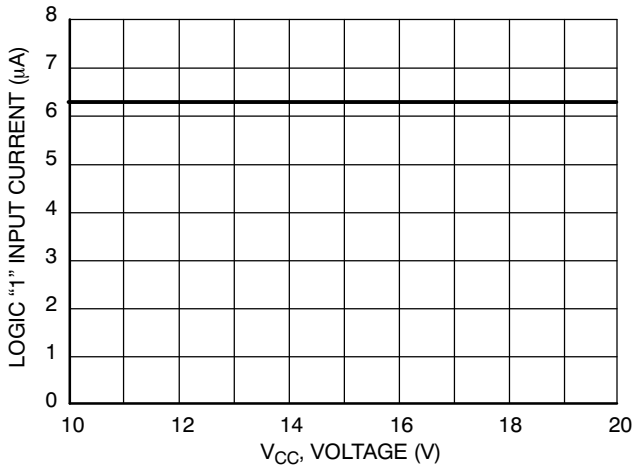


Figure 25. Logic "1" Input Current vs. Supply Voltage ($V_{CC} = V_{BOOT}$)

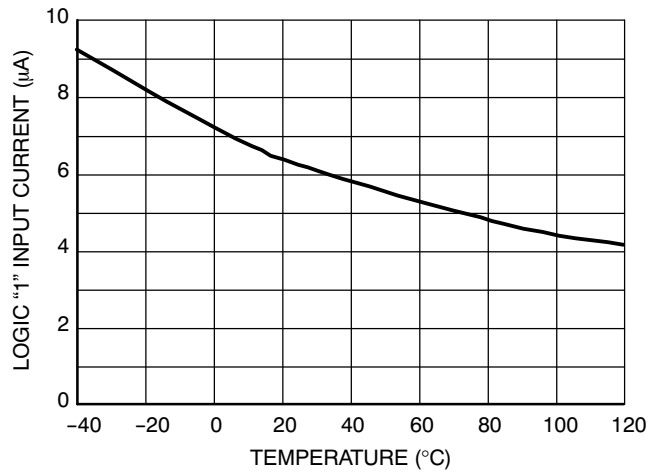


Figure 26. Logic "1" Input Current vs. Temperature

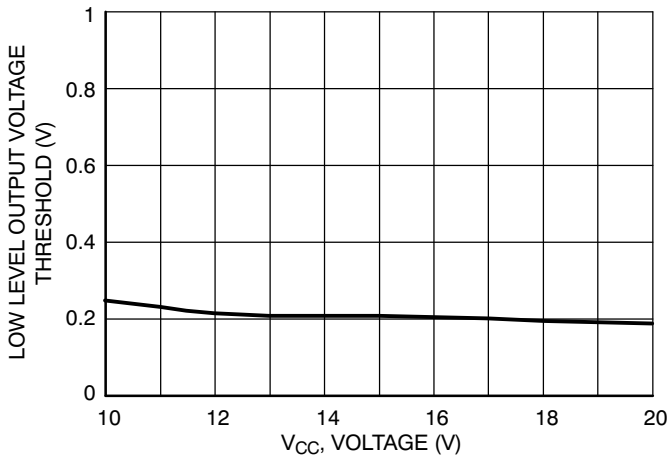


Figure 27. Low Level Output Voltage vs. Supply Voltage ($V_{CC} = V_{BOOT}$)

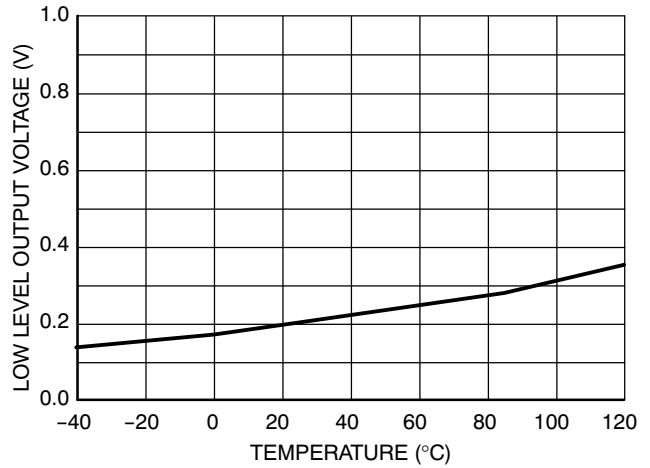


Figure 28. Low Level Output Voltage vs. Temperature

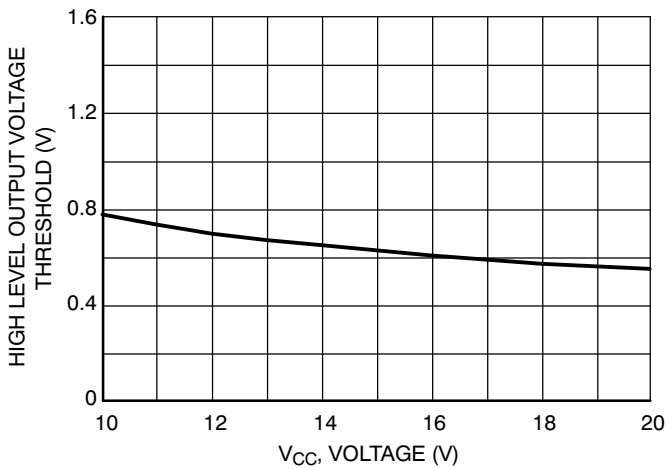


Figure 29. High Level Output Voltage vs. Supply Voltage ($V_{CC} = V_{BOOT}$)

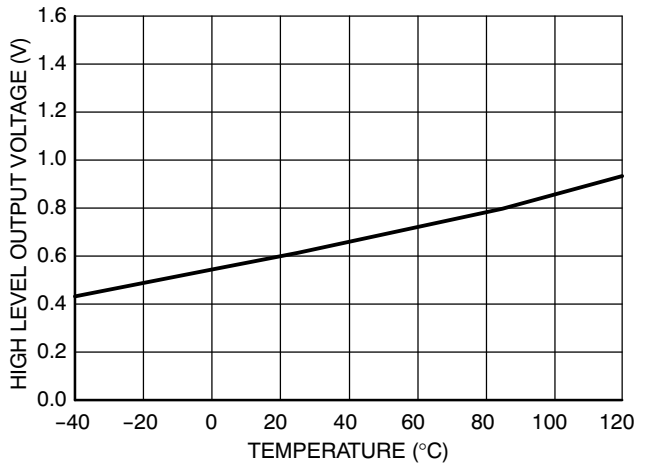


Figure 30. High Level Output Voltage vs. Temperature

CHARACTERIZATION CURVES

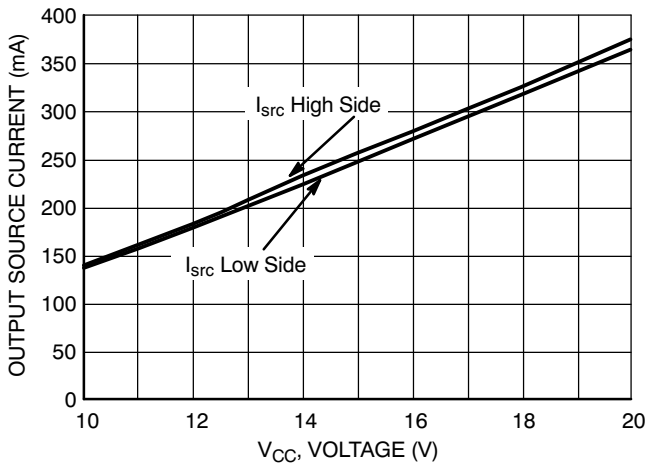


Figure 31. Output Source Current vs. Supply Voltage ($V_{CC} = V_{BOOT}$)

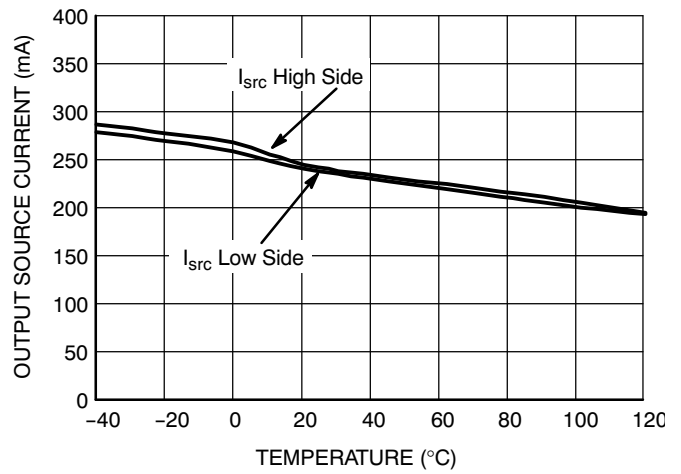


Figure 32. Output Source Current vs. Temperature

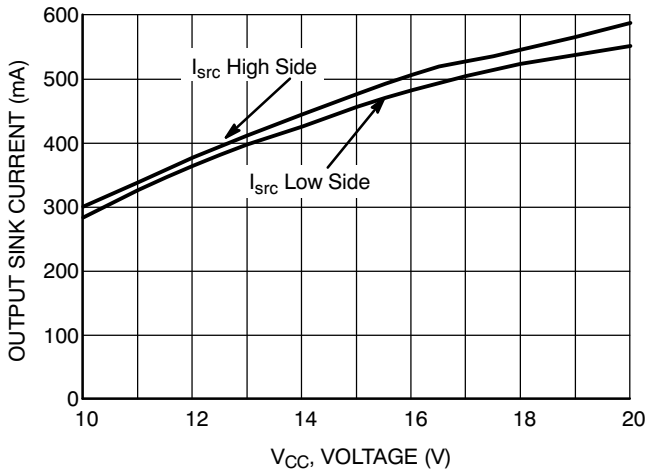


Figure 33. Output Sink Current vs. Supply Voltage ($V_{CC} = V_{BOOT}$)

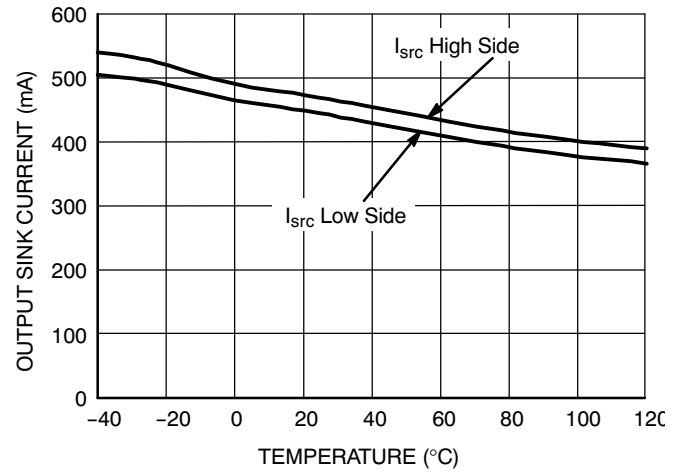


Figure 34. Output Sink Current vs. Temperature

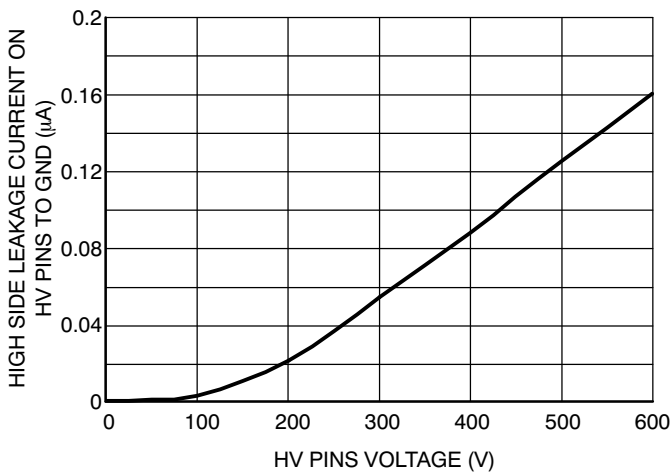


Figure 35. Leakage Current on High Voltage Pins (600 V) to Ground vs. V_{BRIDGE} Voltage ($V_{BRIDGE} = V_{BOOT} = V_{DRV_HI}$)

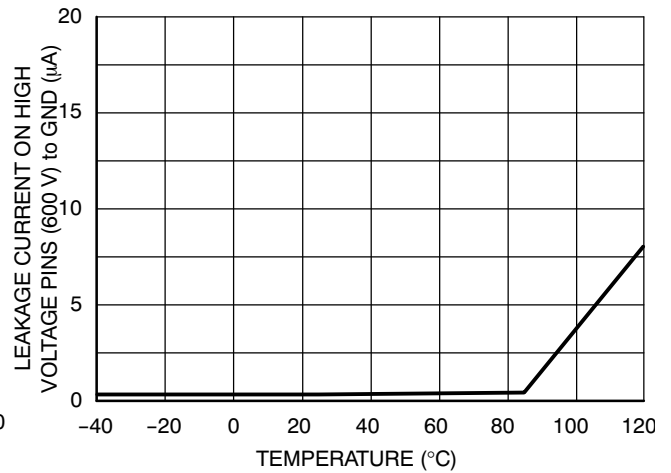


Figure 36. Leakage Current on High Voltage Pins (600 V) to Ground vs. Temperature ($V_{BRIDGE} = V_{BOOT} = V_{DRV_HI} = 600\text{ V}$)

CHARACTERIZATION CURVES

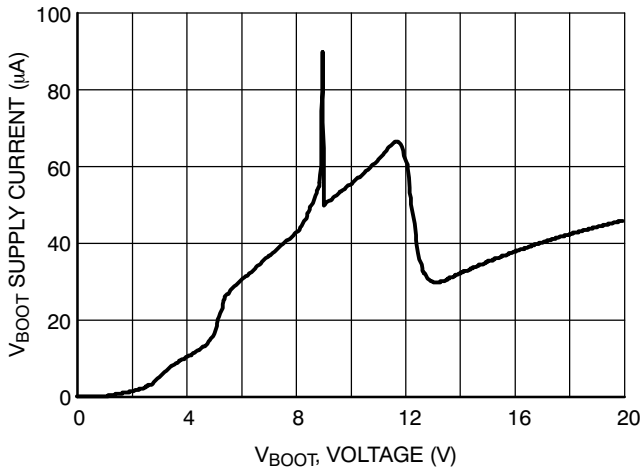


Figure 37. V_{BOOT} Supply Current vs. Bootstrap Supply Voltage

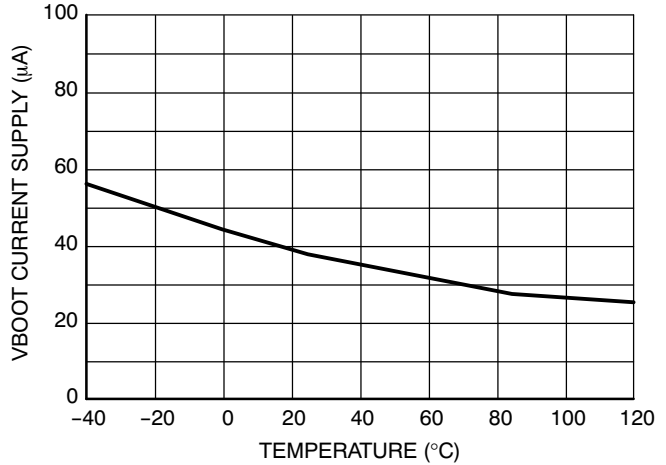


Figure 38. V_{BOOT} Supply Current vs. Temperature

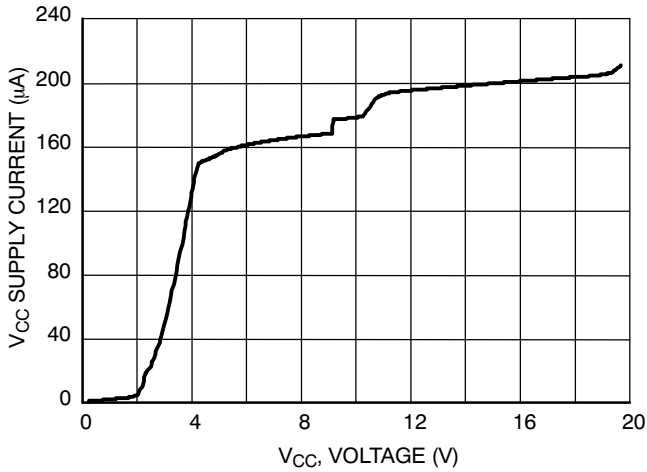


Figure 39. V_{CC} Supply Current vs. V_{CC} Supply Voltage

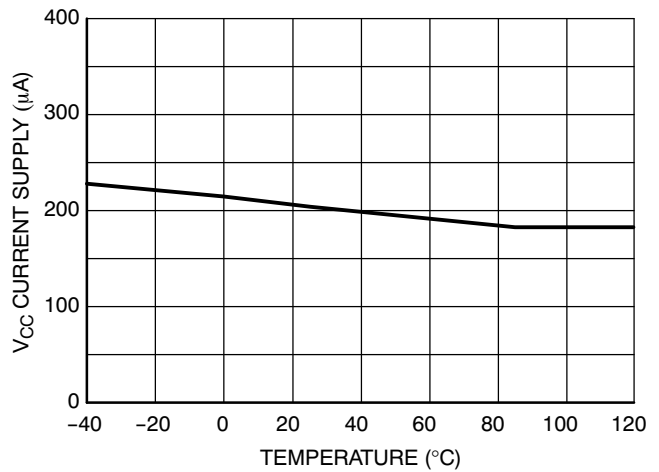


Figure 40. V_{CC} Supply Current vs. Temperature

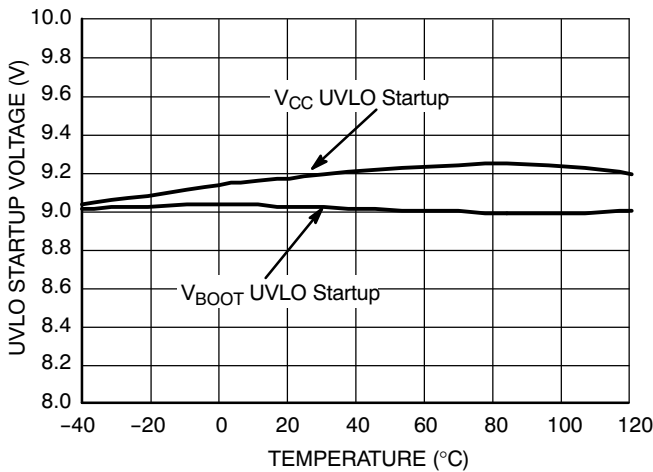


Figure 41. UVLO Startup Voltage vs. Temperature

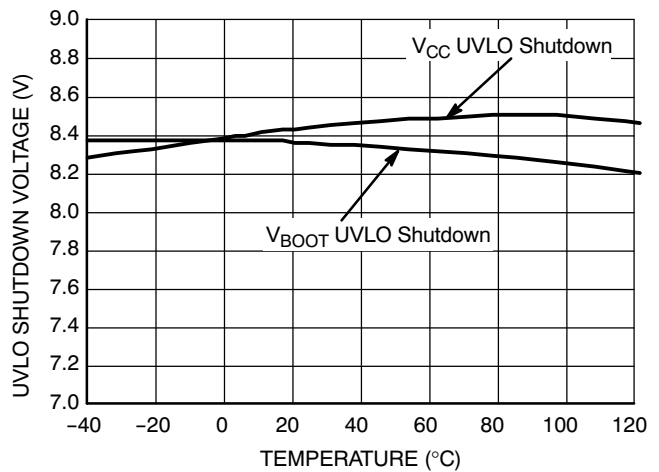


Figure 42. UVLO Shutdown Voltage vs. Temperature

CHARACTERIZATION CURVES

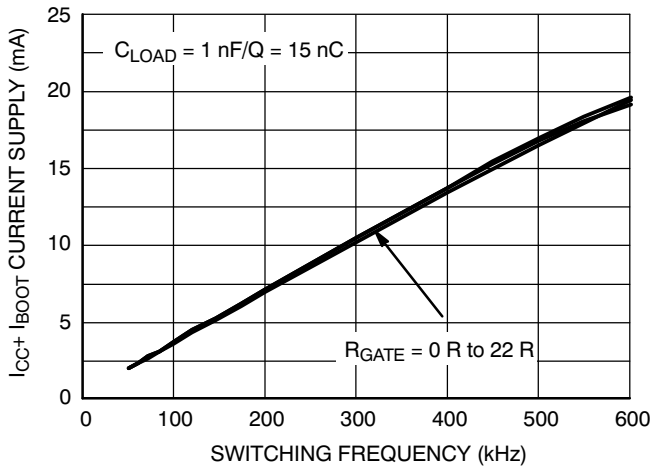


Figure 43. I_{CC1} Consumption vs. Switching Frequency with 15 nC Load on Each Driver @ $V_{CC} = 15 V$

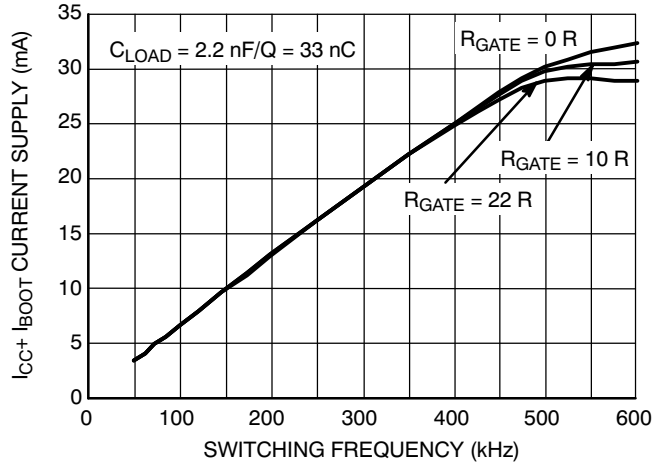


Figure 44. I_{CC1} Consumption vs. Switching Frequency with 33 nC Load on Each Driver @ $V_{CC} = 15 V$

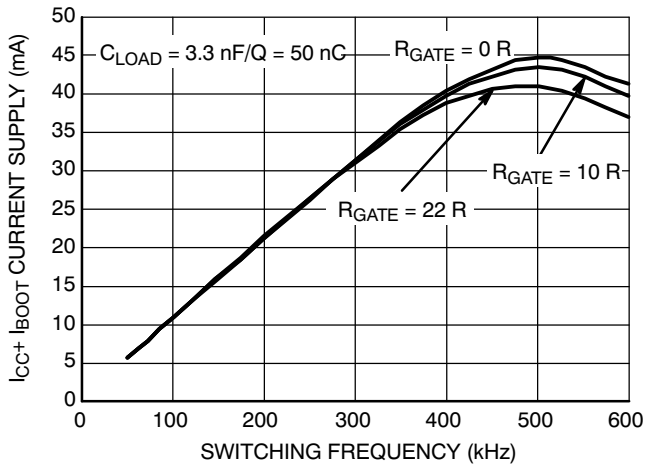


Figure 45. I_{CC1} Consumption vs. Switching Frequency with 50 nC Load on Each Driver @ $V_{CC} = 15 V$

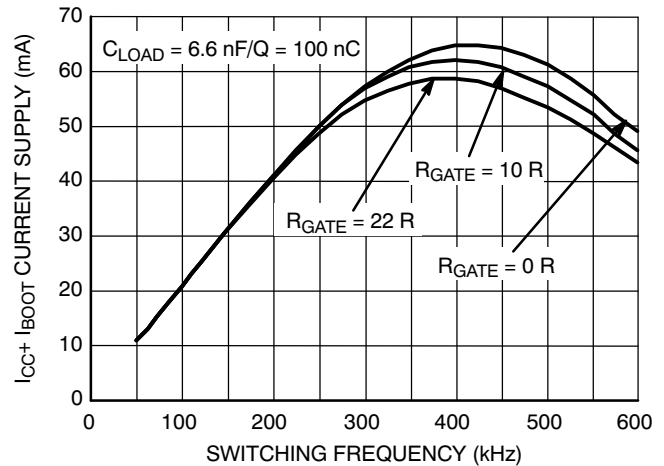
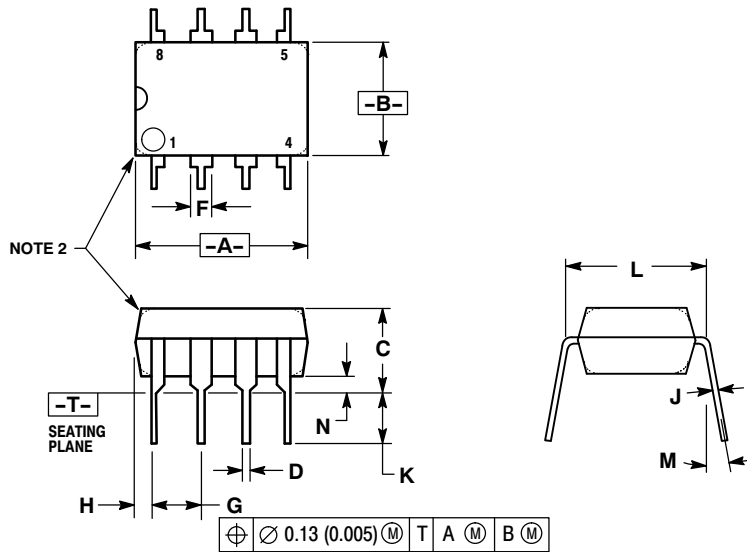


Figure 46. I_{CC1} Consumption vs. Switching Frequency with 100 nC Load on Each Driver @ $V_{CC} = 15 V$

NCP5111

PACKAGE DIMENSIONS

8 LEAD PDIP
CASE 626-05
ISSUE L



NOTES:

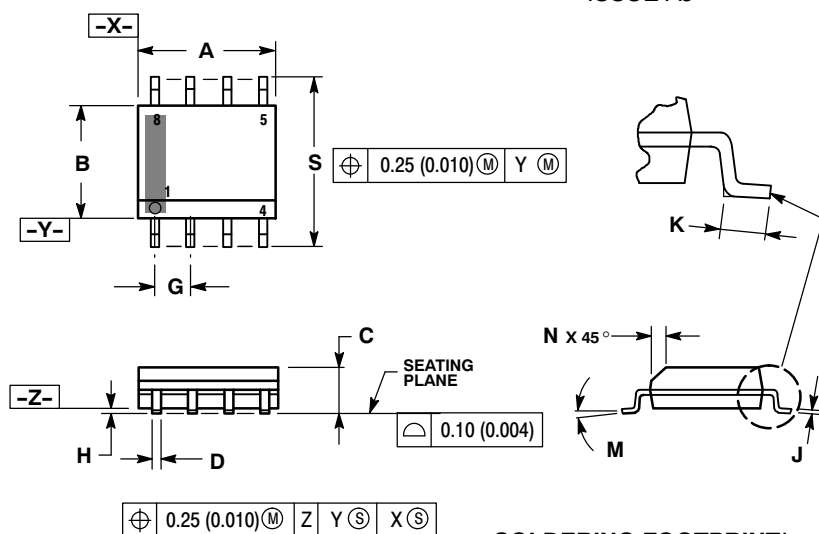
1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.40	10.16	0.370	0.400
B	6.10	6.60	0.240	0.260
C	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	---	10°	---	10°
N	0.76	1.01	0.030	0.040

NCP5111

PACKAGE DIMENSIONS

SOIC-8 NB CASE 751-07 ISSUE AJ

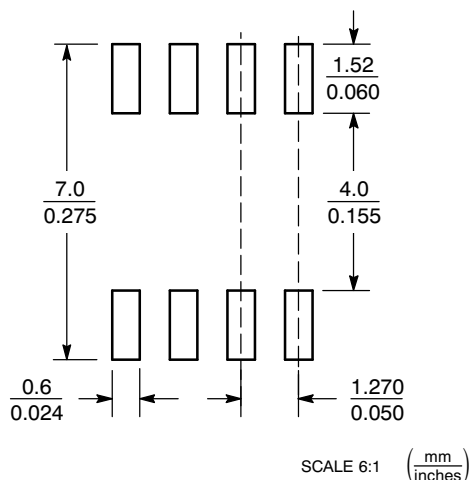


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

The product described herein is covered by U.S. patents: 6,097,075; 7,176,723; 6,362,067. There may be some other patents pending.

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80211 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local Sales Representative

NCP5111/D